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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# Multilayer Varistor for ESD pulse [2 Array Type for high speed signal lines]

Series: **EZJZS** 







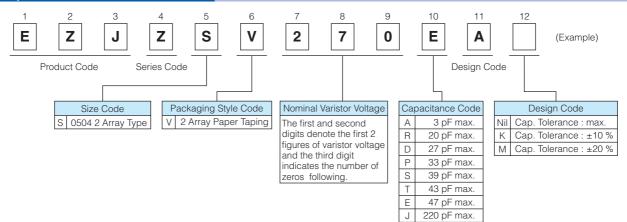
#### **Features**

- Excellent esd suppression due to original advanced material technology
- Having large electrostatic resistance meeting IEC61000-4-2, LEVEL 4 standard
- Having no polarity (bipolar) facilitated replacing zener diodes. Capable of replacing 2 zener diodes and 1 capacitor.
- 2 Array per package for multiple lines
- Lead-free terminal electrodes enabled great solderability
- Wide range of products is available by adopting multilayer structure, meeting various needs
- Ultra low capacitance for signal lines of high speed busses
- Ideal for USB 2.0, IEEE1394, and HDMI high speed data busses
- ROHS compliant

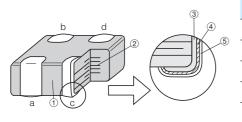
# ■ As for Packaging Methods, Handling Precautions

Please see Data Files

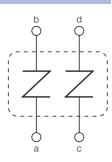




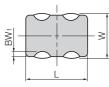
#### Construction



Name			
Semiconductive Ceramics			
Internal electrode			
	Substrate electrode		
Terminal electrode	Intermediate electrode		
	External electrode		
	Semiconduct Internal e		



#### Dimensions in mm (not to scale)





Size(inch)	L	W	T	BW	BW <sub>1</sub>	Р
0504 (2 Array)	1.37±0.15	1.0±0.1	$0.60^{+0.06}_{-0.10}$	0.36±0.10	0.2±0.1	0.64±0.10

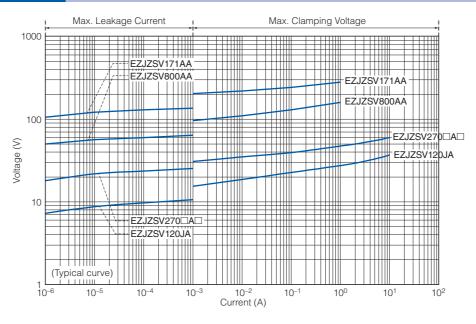


# **Ratings and Characteristics**

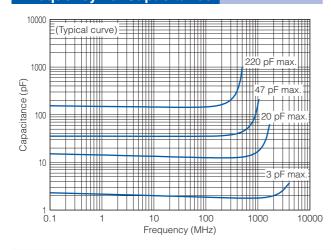
Size	Part No.	Maximum allowable voltage DC (V)	Nominal varistor voltage at 1mA (V)	Capacitance (	·	Maximum peak current at 8/20µs, 2times (A)	Maximum ESD IEC61000-4-2
	EZ 170\/100 IA	` '	` '	at HVII IZ	at 1kHz		
	EZJZSV120JA	6.7	12	220 max. [150 typ.]	175 typ.	5	
	EZJZSV270EA	16	27	47 max. [ 33 typ.]	37 typ.	5	
	EZJZSV270RA	16	27	20 max. [ 15 typ.]	16.5 typ.	3	
	EZJZSV270DA□	16	27	27±10 %/±20 %	30 typ.	5	
0504	EZJZSV270PA□	16	27	33±10 %/±20 %	37 typ.	5	Contact discharge
(2 Array)	EZJZSV270SA□	16	27	39±10 %/±20 %	43 typ.	5	8 kV
	EZJZSV270TA□	16	27	43±10 %/±20 %	47 typ.	5	
	EZJZSV270EA□	16	27	47±10 %/±20 %	52 typ.	5	
	EZJZSV800AA	18	80	3 max. [ 2.1 typ.]	_	_	
	EZJZSV171AA	18	170	3 max. [ 2.1 typ.]	_	_	

- ◆ Operating Temperature Range: –40 to 85 °C
- \* □: Capacitance Tolerance Code K:±10 %, M:±20 %
- \* Avoid flow soldering.

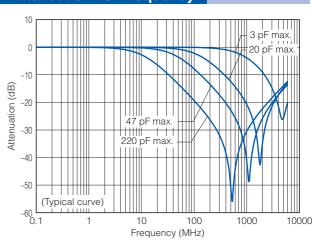
# **Voltage vs. Current**



# Frequency vs. Capacitance



# Attenuation vs. Frequency





#### **Varistor Characteristics and Equivalent Circuit**

A Multilayer Varistor does not have an electrical polarity like zener diodes and is equivalent to total 3 pcs. of 2 zener diodes and 1 capacitor.

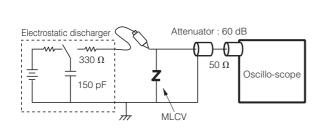
[Equivalent Circuit]

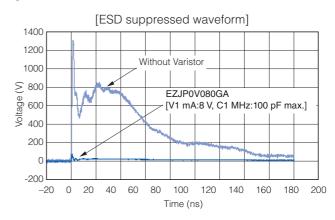


# **ESD Suppressive Effects**

Typical effects of ESD suppression

Test conditions: IEC61000-4-2\* Level 4 Contact discharge, 8 kV



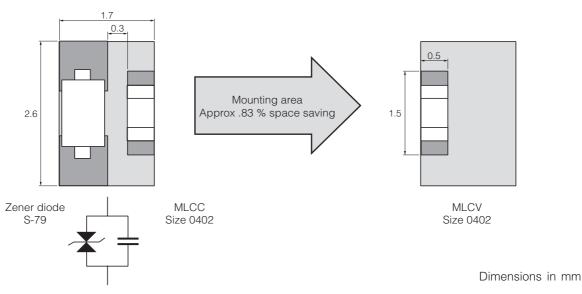


\* IEC61000-4-2 ··· International Standard of the ESD testing method (HBM) for electronic equipment ability to withstand ESD generated from a human body. It sets 4 levels of severity

Severity	Level 1	Level 2	Level 3	Level 4
Contact discharge	2 kV	4 kV	6 kV	8 kV
Air discharge	2 kV	4 kV	8 kV	15 kV

#### Replacement of Zener diode

Replacing "Zener diode and Capacitor" with Multilayer Varistor saves both the mounting area and number of components used.



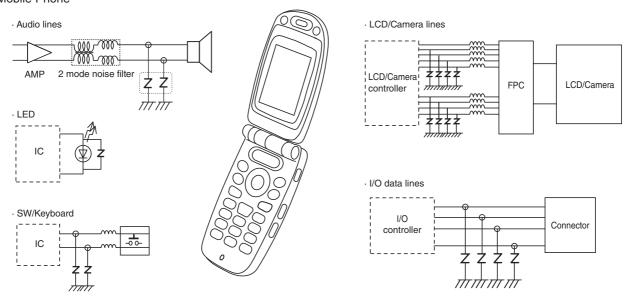


# **Recommended Applications**

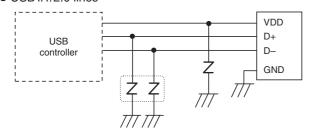
Applications	Series		Circuit DC 1k 1M 1G (Hz)			
Mobile phones, DSC, PC, PDA,	Ultra low capacitance (Cap. : 3 pF or less)					DC to GHz Antenna, RF circuit, LVDS USB, IEEE1394, HDMI etc.
HDD TV (PDP, LC etc.), DVD, DVC, Game consoles, Audio equipment	EZJZ, P	Low capacitance (Cap. : 20 to 680 pF)				DC to tens of Hz PWR, SW, Audio terminals LCD, RS232C, etc.
PWR, Photoelectronic sensors, SSR, Motors, Pressure sensors, Proximity switches	Series EZJS	High capacitance (Cap.: 1800 to 22000 pF)				DC to several kHz PWR, SW, Audio terminals etc.

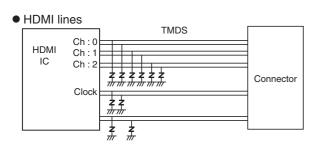
# **Applications**

#### Mobile Phone

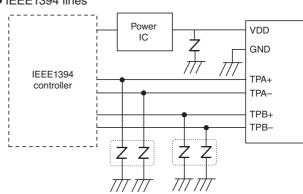


# ● USB1.1/2.0 lines





#### • IEEE1394 lines





Perf	formance and	Testin	ig Metl	hods

Characteristics	Specifications	Testing Method		
Standard test conditions		Electrical characteristics shall be measured under the following conditions. Temp. : 5 to 35 °C, Relative humidity : 85 % or less		
Varistor voltage	To meet the specified value.	The Varistor voltage is the voltage (V <sub>c</sub> ,or V <sub>cmA</sub> ) between both end terminals of a Varistor when specified current (CmA) is applied to it. The measurement shall be made as quickly as possible to avoid heating effects.		
Maximum allowable voltage	To meet the specified value.	The maximum DC voltage that can be applied continuously to a varistor.		
Capacitance	To meet the specified value.	Capacitance shall be measured at the specified frequency, bias voltage 0 V, and measuring voltage 0.2 to 2 Vrms.		
Maximum peak current	To meet the specified value.	The maximum current measured (Varistor voltage tolerance is within ±10 %) when a standard impulse current of 8/20 µ seconds is applied twice with an interval of 5 minutes.		
Maximum ESD	To meet the specified value.	The maximum ESD measured (while the varistor voltage is within ±30 % of its nominal value) when exposed to ESD 10 times (five times for each positive-negative polarity) based on IEC61000-4-2.		
Solder ability	To meet the specified value.	The part shall be immersed into a soldering bath under the conditions below.  Solder: H63A  Soldering flux : Ethanol solution of rosin (Concentration approx. 25 wt%)  Soldering temp. : 230±5 °C  Period : 4±1 s  Soldering position: Immerse both terminal electrodes until they are completely into the soldering bath.		
Resistance to soldering heat	ΔVc / Vc : within ±10 %	After the immersion, leave the part for 24 ±2 hours under the standard condition, then evaluate its characteristics. Soldering conditions are specified below:  Soldering conditions: 270 °C, 3 s / 260 °C, 10 s  Soldering position: Immerse both terminal electrodes until they are completely into the soldering bath.		
Temperature cycling	ΔVc / Vc : within ±10 %	After repeating the cycles stated below for specified number of times, le the part for 24±2 hours, then evaluate its characteristics.  Cycle: 5 cycles  Step Temperature Period  1 Max. Operating Temp. 30±3 min  2 Ordinary temp. 3 min max.  3 Min. Operating Temp. 30±3 min  4 Ordinary temp. 3 min max.		
Biased Humidity	ΔVc / Vc : within ±10 %	After conducting the test under the conditions specified below, leave the part 24±2 hours, then evaluate its characteristics.  Temp. : 40±2 °C  Humidity : 90 to 95 %RH  Applied voltage : Maximum allowable voltage (Individually specified)  Period : 500+24 / 0 h		
High temperature exposure (dry heat)	ΔVc / Vc : within ±10 %	After conducting the test under the conditions specified below, leave the part 24 ±2 hours, then evaluate its characteristics.		